

SPICE Device Model SUM110N03-04P Vishay Siliconix

N-Channel 30-V (D-S) 175°C MOSFET

CHARACTERISTICS

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS

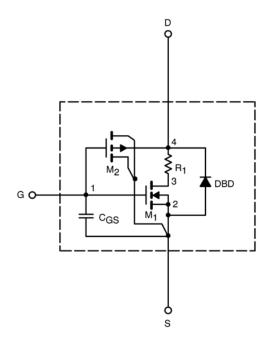
- Apply for both Linear and Switching Application
- Accurate over the -55 to 125°C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

DESCRIPTION

The attached spice model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the -55 to 125° C temperature ranges under the pulsed 0 to 10V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched $C_{\rm gd}$ model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device

SUBCIRCUIT MODEL SCHEMATIC



This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

Document Number: 72423 www.vishay.com 09-Jun-04 1

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SPECIFICATIONS (T _J = 25°C UNLESS OTHERWISE NOTED)					
Parameter	Symbol	Test Conditions	Simulated Data	Measured Data	Unit
Static					
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1.8		V
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	1375		Α
Drain-Source On-State Resistance ^a	r _{DS(on)}	V_{GS} = 10 V , I_D = 20 A	0.0033	0.0033	Ω
		V_{GS} = 10 V, I_{D} = 20 A, T_{J} = 125°C	0.0049		
		V_{GS} = 10 V, I_{D} = 20 A, T_{J} = 175°C	0.0058		
		V _{GS} = 4.5 V, I _D = 20 A	0.0052	0.0052	
Forward Transconductance ^a	g _{fs}	$V_{DS} = 15 \text{ V}, I_{D} = 20 \text{ A}$	70		S
Forward Voltage ^a	V_{SD}	I _S = 100 A, V _{GS} = 0 V	0.92	1.2	V
Dynamic ^b					
Input Capacitance	C _{iss}	V _{GS} = 0 V, V _{DS} = 25 V, f = 1 MHz	5194	5100	Pf
Output Capacitance	Coss		780	860	
Reverse Transfer Capacitance	C _{rss}		292	430	
Total Gate Charge ^c	Q_g	V_{DS} = 15 V, V_{GS} = 4.5 V, I_{D} = 50 A	43	40	NC
Gate-Source Charge ^c	Q_{gs}		18	18	
Gate-Drain Charge ^c	Q_{gd}		16	16	
Turn-On Delay Time ^c	t _{d(on)}	$V_{DD} = 15 \text{ V}, \text{ R}_L = 0.30 \ \Omega$ $I_D \cong 50 \text{ A}, \text{ V}_{GEN} = 10 \text{ V}, \text{ R}_G = 2.5 \ \Omega$	13	12	- Ns
Rise Time ^c	t _r		15	12	
Turn-Off Delay Time ^c	t _{d(off)}		31	40	
Fall Time ^c	t _f		31	10	

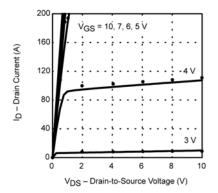
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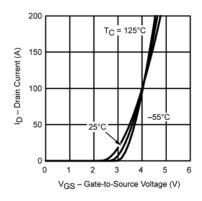
a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2%. b. Guaranteed by design, not subject to production testing. c. Independent of operating temperature.

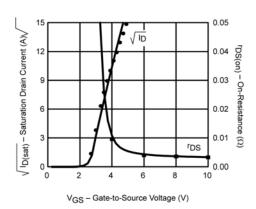


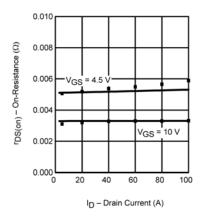
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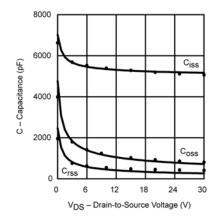
COMPARISON OF MODEL WITH MEASURED DATA (TJ=25°C UNLESS OTHERWISE NOTED)

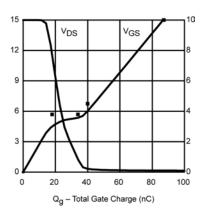












Note: Dots and squares represent measured data



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Document Number: 91000 Revision: 18-Jul-08

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